NSN 5961-01-594-3765

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Overall Length:
Between 1.172 inches and 1.182 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.235 inches and 0.245 inches
Mounting Facility Quantity:
3
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 breakdown voltage, dc
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius ambient air
Special Features:
Planar photodiode in a flat window three lead to-5 package; chip is isolated from the case; diodes have very high shunt resistance and good
plue response
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Filg:
A110a0